

Innovating Energy Technology

2MBI550VX-170-50

IGBT Modules

Power Module (V series) 1700V / 550A / 2-in-1 package

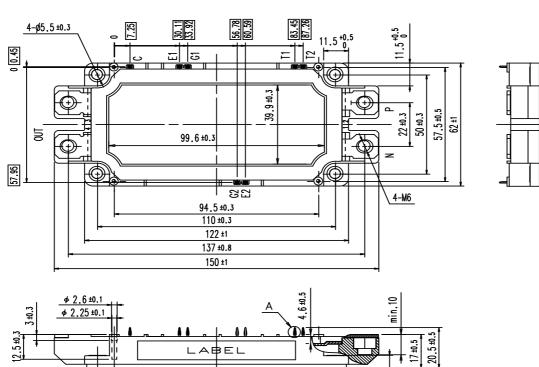
Features

Low V_{CE(sat)} Low Inductance Module structure Solderless press-fit terminals

Applications

Inverter for Motor Drives, AC and DC Servo Drives Uninterruptible Power Supply Systems, Wind Turbines, PV Power Conditioning Systems

■ Outline drawing (Unit : mm)



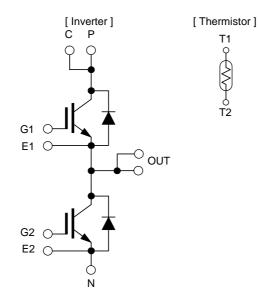
Τ1

NOTE) MARKED SIDE WITH A TOLERANCE OF 4 00.5

Weight: 350g (typ.)

6.5±0.5

Equivalent Circuit



FM5F8406 2014/11







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■ Absolute Maximum Ratings (at T_c= 25°C unless otherwise specified)

| | Items | Symbols | Cond | litions | Maximum Ratings | Units |
|--------------------------------|---------------------------------------|-----------------------|------------|----------------------|--------------------|-------|
| Collector- | Emitter voltage | V _{CES} | | | 1700 | V |
| Gate-Emit | ter voltage | V _{GES} | | | ±20 | V |
| | | 1 | Continuous | T _C =25°C | 750 | |
| | | I _C | Continuous | $T_{C}=100^{\circ}C$ | 550 | |
| Collector of | current | l _c pulse | 1ms | | 1100 | Α |
| | | -I _C | | | 550 | |
| | | -I _C pulse | 1ms | | 1100 | |
| Collector power dissipation | | P _C | 1 device | | 3750 | W |
| Junction temperature | | Tj | | | 175 | |
| Operating junction temperature | | T _{jop} | | | 450 | |
| (under switching conditions) | | | | | 150 | °C |
| Case temperature | | T _c | | | 125 | |
| Storage temperature | | T _{stg} | | | -40 ~ 125 | |
| Isolation | between terminal and copper base (*1) | V | AC: 1min. | | 3400 | VAC |
| voltage | between thermistor and others (*2) | V _{iso} | AC. Imin. | | 3400 | VAC |
| Screw | Mounting (*3) | - | | | 3.5 | Nm |
| Torque Terminals (*4) | | - | | | 4.5 | |

(*1) All terminals should be connected together during the test.

(*2) Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

(*3) Recommendable Value : 2.5-3.5 Nm (M5)

(*4) Recommendable Value : 3.5-4.5 Nm (M6)



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| Electrical characteristics (at T _j = | 25°C unless otherwise specified) |
|---|----------------------------------|
|---|----------------------------------|

| Itomo | Symbolo | ols Conditions | | Characteristics | | | Unite |
|--|------------------------------------|---|-----------------------|-----------------|------|------|-------|
| Items | Symbols | | | min. | typ. | max. | Units |
| Zero gate voltage Collector current | I _{CES} | V _{GE} =0V, V _{CE} =1700V | | - | - | 3.0 | mA |
| Gate-Emitter leakage current | I _{GES} | V _{CE} =0V, V _{GE} =±20V | | - | - | 600 | nA |
| Gate-Emitter threshold voltage | $V_{GE(th)}$ | V_{CE} =20V, I_{C} = | | 6.0 | 6.5 | 7.0 | V |
| | N/ | | T _j =25°C | - | 2.90 | 3.35 | |
| | V _{CE(sat)} (terminal) | | T _j =125°C | - | 3.35 | - | |
| Collector-Emitter | (terminal) | $V_{GE} = 15V$ | T _j =150°C | - | 3.55 | - | |
| saturation voltage | | I _C = 550A | T _j =25°C | - | 2.15 | 2.60 | - V |
| | V _{CE(sat)} (chip) | | T _i =125°C | - | 2.70 | - | |
| | | | T _i =150°C | - | 2.80 | - | - |
| Internal gate resistance | R _{G(int)} | - | | - | 1.67 | - | Ω |
| Input capacitance | C _{ies} | V _{CE} =10V, V _{GE} | =0V, f=1MHz | - | 40 | - | nF |
| | t _{on} | | | - | 1000 | - | |
| Turn-on time | t _r | V _{CC} = 900V | I _C = 550A | - | 500 | - | |
| | t _{r(i)} | $V_{GE} = \pm 15V$ | R _G = 3.3Ω | - | 120 | - | nsec |
| Turn-off time | t _{off} | L _s = 80nH | | - | 1300 | - | |
| | t _f | | | - | 100 | - | |
| | N/ | | T _j =25°C | - | 2.70 | 3.15 | |
| | V _F | | T _j =125°C | - | 3.00 | - | |
| | (terminal) | $V_{GE} = 0V$ | T _i =150°C | - | 2.95 | - | |
| Forward on voltage | V _F (chip) | I _F = 550A | T _i =25°C | - | 1.95 | 2.40 | - V |
| | | | T _i =125°C | - | 2.25 | - | |
| | | | T _i =150°C | - | 2.20 | - | _ |
| Reverse recovery time | t _{rr} | I _F = 550A | , | - | 250 | - | nsec |
| Thermistor Resistance | R | T=25°C | | - | 5000 | - | Ω |
| THEITHISTOL RESISTING | ĸ | T=100°C | | 465 | 495 | 520 | 12 |
| Thermistor B value | rmistor B value B T=25/50°C | | 3305 | 3375 | 3450 | K | |

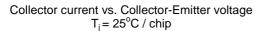
5. Thermal resistance characteristics

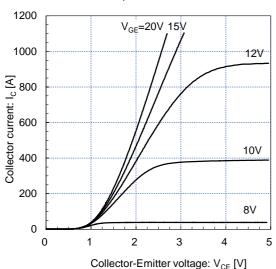
| Items | Symbols | Conditions | Characteristics | | | Units |
|---|----------------------|-----------------------|-----------------|--------|------|-------|
| items | | | min. | typ. | max. | Units |
| Thermal resistance | P | IGBT | - | - | 0.04 | |
| (1device) | R _{th(j-c)} | FWD | - | - | 0.06 | °C/W |
| Contact thermal resistance (1device) (*1) | $R_{th(c-f)}$ | with thermal compound | - | 0.0167 | - | 0/00 |

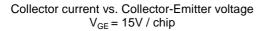
(*1) This is the value which is defined mounting on the additional cooling fin with thermal compound.

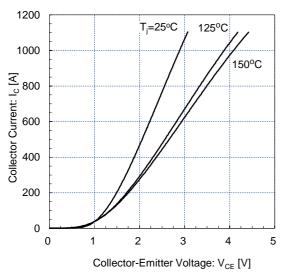


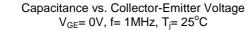
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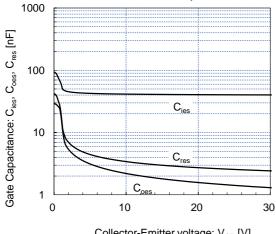




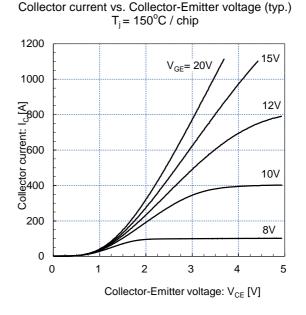




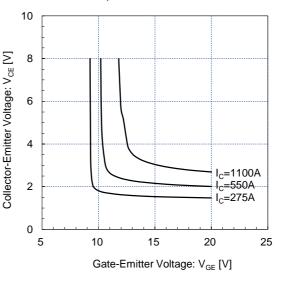


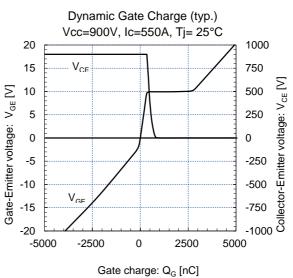


Collector-Emitter voltage: V_{CE} [V]



Collector-Emitter voltage vs. Gate-Emitter voltage $T_i = 25^{\circ}C / chip$





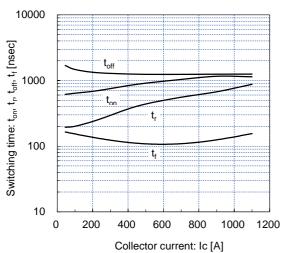




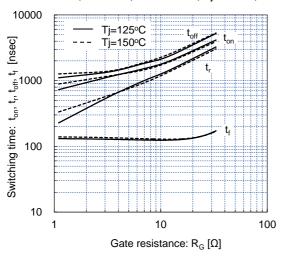
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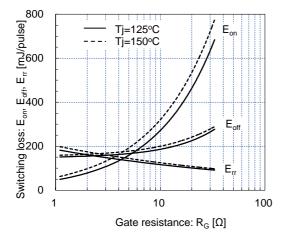
Switching time vs. Collector current (typ.) Vcc=900V, VGE= \pm 15V, Rg= 3.3Ω , Tj= 25° C



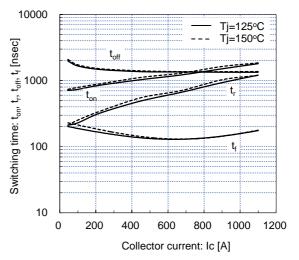
Switching time vs. Gate resistance (typ.) /cc=900V, Ic=550A, VGE=±15V, Tj=125°C, 150°(



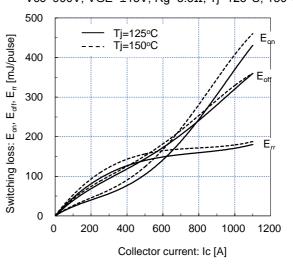
Switching loss vs. Gate resistance (typ.) /cc=900V, Ic=550A, VGE=±15V, Tj=125°C, 150°(



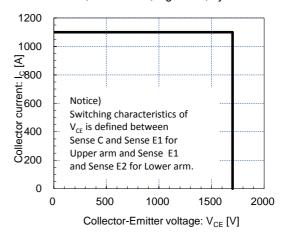
Switching time vs. Collector current (typ.) Vcc=900V, VGE=±15V, Rg=3.3Ω, Tj=125°C, 150°C



Switching loss vs. Collector current (typ.) Vcc=900V, VGE=±15V, Rg=3.3Ω, Tj=125°C, 150°C

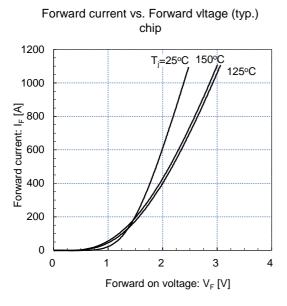


Reverse bias safe operating area (max.) +VGE=15V, -VGE=15V, Rg=3.3Ω, Tj=150°C

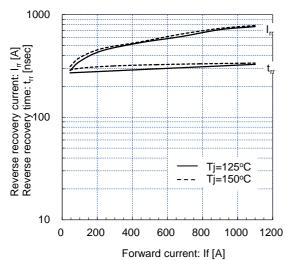


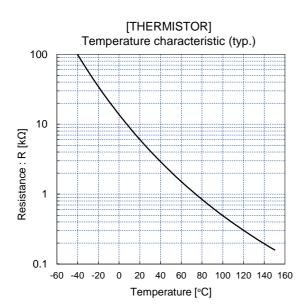


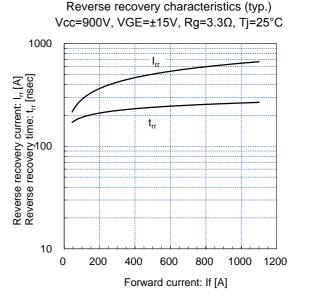
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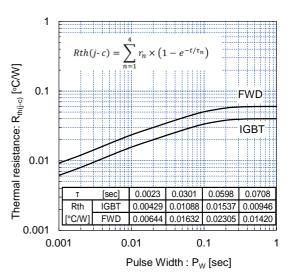
Reverse Recovery Characteristics (typ.) Vcc=900V, VGE=±15V, Rg=3.3Ω, Tj=125°C,150°C

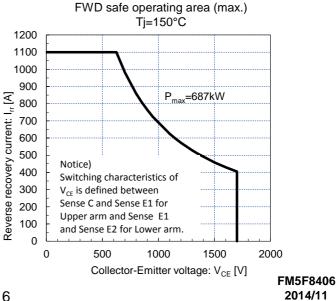






Transient Thermal Resistance (max.)







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|---|---|
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